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TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

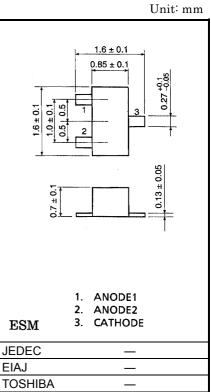
1SS385F

High Speed Switching

- Low forward voltage: $V_F = 0.23V$ (typ.) @I_F = 5mA
- Ultra-small package •

Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|--------------------------------|------------------|---------|------|
| Maximum (peak) reverse Voltage | V _{RM} | 15 | V |
| Reverse voltage | V _R | 10 | V |
| Maximum (peak) forward current | I _{FM} | 200 (*) | mA |
| Average forward current | Ι _Ο | 100 (*) | mA |
| Surge current (10ms) | I _{FSM} | 1 (*) | А |
| Power dissipation | Р | 100 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | -55~125 | °C |
| Operating temperature range | T _{opr} | -40~100 | °C |



*: Unit rating. Total rating = unit rating × 1.5

Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min. | Тур. | Max. | Unit |
|-------------------|--------------------|-----------------|--|------|------|------|------|
| Forward voltage | V _{F (1)} | _ | I _F = 1mA | _ | 0.18 | _ | V |
| | V _{F (2)} | _ | I _F = 5mA | | 0.23 | 0.30 | V |
| | V _{F (3)} | — | I _F = 100mA | | 0.35 | 0.50 | V |
| Reverse current | Ι _R | _ | V _R = 10V | _ | _ | 20 | μA |
| Total capacitance | CT | _ | V _R = 0, f = 1MH _z | _ | 20 | 40 | pF |

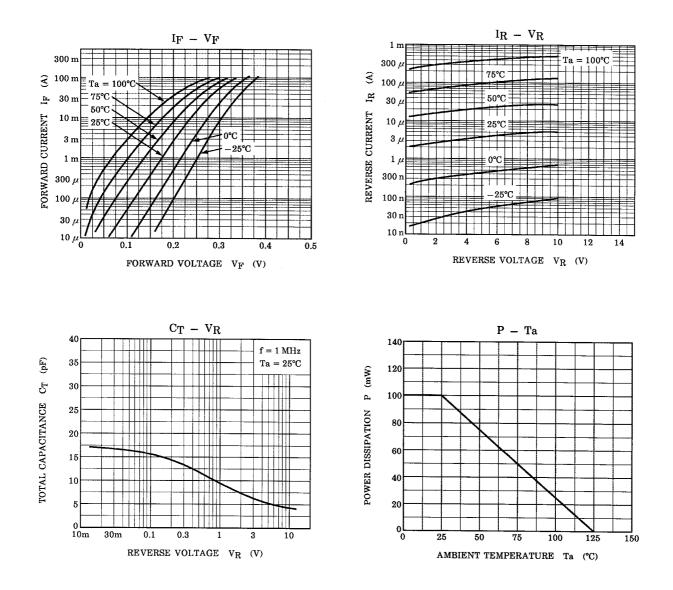
Equivalent Circuit (Top View)





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